UNİSYS

DATE:

August 17, 1994

PPM-94-018

TO:

T. Mecum/311.1

FROM:

K. Salm/300.1

SUBJECT:

Radiation Report on FUSE

Part No. EL2243C Control No. 11024

cc:

A. Sharma/311 Library/300.1

A radiation evaluation was performed on EL2243C (Dual Operational Amplifier) to determine the total dose tolerance of these parts. A brief summary of the test results is provided below. For detailed information, refer to Tables I through IV and Figure 1.

The total dose testing was performed using a cobalt-60 gamma ray source. During the radiation testing, eight parts were irradiated under bias (see Figure 1 for bias configuration), and two parts were used as control samples. The total dose radiation levels were 5, 10, 15, 20, 30, 50, 75 and 100 krads*. The dose rate was between 0.075 and 1.5 krads/hour, depending on the total dose level (see Table II for radiation schedule). After the 100 krad irradiation, parts were annealed at 25°C for 168 hours, after which the parts were annealed at 100°C for 168 hours. After each radiation exposure and annealing treatment, parts were electrically tested according to the test conditions and the specification limits** listed in Table III.

At initial electrical measurements the +PSRR2 and -PSRR2 reading for four parts, S/N 33, S/N 36, S/N 37, and S/N 38, read less than the minimum specification limit of 80 dB, with values in the range of 75 dB to 79.8 dB. From the 5 krad irradiation level up to and including the 15 krad irradiation level, three of the parts continued to read less than the minimum specification limit for +PSRR2 and -PSRR2, with values in the same range. S/N 8 recovered to within specification limits at the 10 krad irradiation level.

After the 20 krad irradiation level, the same failures continued for +PSRR2 and -PSRR2 and S/N 32 exceeded the maximum specification limit of ± 5 mV for Viol, with a reading of 5.1 mV.

At the 30, 50 and 75 krad levels, the same failures continued with the parts reading the same values. At the 100 krad irradiation level, the same parts continued to read less than the minimum specification limit for +PSRR2 and -PSRR2, with readings in the range of 75dB to 77 dB respectively, and S/N 32 continued to exceed the maximum specification limit for Viol with a reading of 5.5 mV.

After annealing for 168 hours at 25°C, S/N 33, S/N 36 and S/N 37 continued to read less than the minimum specification limit for +PSRR2 and -PSRR2, with readings in the range of 75dB to 78 dB respectively, and S/N 32 continued to exceed the maximum specification limit for Viol with a reading of 5.4 mV.

After annealing for 168 hours at 100°C, no rebound effects were observed in the parts.

^{*}The term rads, as used in this document, means rads(silicon). All radiation levels cited are cumulative.

^{**}These are manufacturer's non-irradiation data specification limits. No post-irradiation limits were provided by the manufacturer at the time these tests were performed.

Table IV provides a summary of the mean and standard deviation values for each parameter after different irradiation exposures and annealing steps.

Any further details about this evaluation can be obtained upon request. If you have any questions, please call me at (301) 731-8954.

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TABLE I. Part Information

Generic Part Number:

EL2243C

FUSE

Part Number:

EL2243C

FUSE

Control Number:

11024

Charge Number:

C44430

Manufacturer:

Elantec

Lot Date Code:

9332C

Quantity Tested:

10

Serial Number of

Control Sample:

30, 31

Serial Numbers of

Radiation Sample:

32, 33, 34, 35, 36, 37, 38, 39

Part Function:

Dual Op-Amp

Part Technology:

Linear

Package Style:

8 Pin DIP

Test Equipment:

A540

Test Engineer:

C. Nguyen

^{*} No radiation tolerance/hardness was guaranteed by the manufacturer for this part.

TABLE II. Radiation Schedule for EL2243C

EVENTS	DATE
1) INITIAL ELECTRICAL MEASUREMENTS	06/23/94
2) 5 KRAD IRRADIATION (0.25 KRADS/HOUR)	06/23/94
POST-5 KRAD ELECTRICAL MEASUREMENT	06/24/94
3) 10 KRAD IRRADIATION (0.075 KRADS/HOUR)	06/24/94
POST-10 KRAD ELECTRICAL MEASUREMENT	06/27/94
4) 15 KRAD IRRADIATION (0.25 KRADS/HOUR)	06/27/94
POST-15 KRAD ELECTRICAL MEASUREMENT	06/28/94
5) 20 KRAD IRRADIATION (0.25 KRADS/HOUR)	06/28/94
POST-20 KRAD ELECTRICAL MEASUREMENT	06/29/94
6) 30 KRAD IRRADIATION (0.5 KRADS/HOUR)	06/29/94
POST-30 KRAD ELECTRICAL MEASUREMENT	06/30/94
7) 50 KRAD IRRADIATION (0.6 KRADS/HOUR) POST-50 KRAD ELECTRICAL MEASUREMENT (Power outage occurred after 29 hours. Parts annealed at room temperature under bias for 2.5 days. Dose rate was then adjusted to complete irradiation within 23 hours.)	07/01/94 07/06/94
8) 75 KRAD IRRADIATION (1.25 KRADS/HOUR)	07/06/94
POST-75 KRAD ELECTRICAL MEASUREMENT	07/07/94
9) 100 KRAD IRRADIATION (1.5 KRADS/HOUR)	07/07/94
POST-100 KRAD ELECTRICAL MEASUREMENT	07/08/94
10) 168-HOUR ANNEALING @25°C	07/08/94
POST-168 HOUR ANNEAL ELECTRICAL MEASUREMENT	07/15/94
11) 168-HOUR ANNEALING @100°C*	07/14/94
POST-168 HOUR ANNEAL ELECTRICAL MEASUREMENT	07/21/94

PARTS WERE IRRADIATED AND ANNEALED UNDER BIAS; SEE FIGURE 1.

^{*}High temperature annealing is performed to accelerate long term time dependent effects (TDE), namely, the "rebound" effect due to the growth of interface states after the radiation exposure. For more information on the need to perform this test, refer to MIL-STD-883D, Method 1019, Para. 3.10.1.

Table III. Electrical Characteristics of EL2243C

TEST CONDITIONS: VSS= +/- 15V unless otherwise noted;

Test temperature : 25oC

tst #	Test name	Min	Max
1	Idd	0.0 ma	10.0 ma
2	Iss	-10.00 ma	0.00 ma
3	Voh1	12.0 v	t .
4	Voh2	12.0 v	
5	Voll	•	-12.0 v
6	Vol2		-12.0 v
7	vio 1		5.0 mv
8	vio 2		5.0 mv
9	+ibias 1		700.0 na
10	+ibias 2		700.0 na
11	-ibias 1		700.0 na
12	-ibias 2		700.0 na
13	iio 1	-100.0 na	100.0 na
14	iio 2	-100.0 na	100.0 na
. 15 16	+Avs 1 (V/mv) +Avs 2 (V/mv)		
17	cmrr 1	80.0 db	
18	cmrr 2	db 0.08	
19 20	+psrr 1 +psrr 2	db 0.08	•
21 22	-psrr 1 -psrr 2	80.0 db	
23	+Iout	-50.00 ma	0.00 ma
24	+Iout	-50.00 ma	0.00 ma
25	-Iout	0.00 ma	50.00 ma
26	-Iout	0.00 ma	50.00 ma

TABLE IV: Summary of Electrical Measurements after Total Dose Exposures and Annealing for EL2243C /1

							Total Dose Exposure (TDE) (krads)												Annealing						
						10		Total			<u>ве дхрова.</u> 2 0		J. 1. 1. 1. 1. 1. 1. 1. 1. 1. 1. 1. 1. 1.	50		75		100				168 }			
	I		Turc.	<u>In</u> itials		5			13		20		30		1		\				@ 25°	°C	@100	Coc	
		Spet. I					- 4		sd	i mean	sd	mean	sd	mean	sđ	mean	sol.	mean	sd_	πean	sd	me <u>an</u>		mean	
<u>Parameters</u>				mean	<u>sđ</u>	mean		mean	0.2	8.2	0.2	8.2	3.2	6.20	D.2	8,2	0.2	8.2	0.2	B 2	0.2	3.2	0.2	9.2	0.2
144	K.A	0	10		0.13	-B 2	0.13	9 2	0.13	-6.2	0.13	-8 2	0.13	8.2	0.13	-E.2	0.13	-8.2	0.13	8.2	2.13	-8,2	3.13	+8-2	0.13
1ss	mA.	-10	0	6,2		13 4	0.11	12.4	0.11	13.4	0.11	13,4	0.11	13.4	0.11	13.4	0.11	13,4	3.11	13.4	0.11	13.4	5,11	13.4	0.11
Voh1	···V	12		13.4	0.11	*******	0.11	13.4	0.11	13.4	3.11	13.4	0.11	13.4	0.11	13.4	0.11	13, 4	0.11	13.4	0.11	13.4	0.11	1374	0.11
Voh2	. V	12	-12	13.4	0.11	13.4	0.11	-14.2	0.08	-14.2	2.06	*11	0.08	-14.2	0,28	-14.2	0.08	-14:2	0.06	*11 2	0.08	-14.2	0.08	*14.2	0.08
Vol1	V		-12	14.2	0.08	-14.2		33.32	0.03	-11.2	0.08	-14.2	0.08	-14.2	0.08	-14.2	0.06	-14-7	0.08	-11.2	0.08	-14.2	0.08	-14.2	· -
Vol2				-14.2	0.0E	+14.2	0.08	4.2		£, 54	2.6	0.56	2.6	0.65	2.E	0.86	2.6	0.91	2.6	0.98	2.7	0.86	2.7	D.77	2.5
Viol	πV	-5	5	2.2	1,5	0.73	2.3	0-49		+0.47	2.5	-0.45	2.5	-0.46	2.5	-0.38	2.5	-1.1	2.7	-tr, t	2.5	-0.35	2.5	-0.42	-
Vio2	mV]	-5	5	÷0.5	2,5	+0.5	2.4	-0.52	2.6	390	11.9	395	13.2	395	13.4	405	12.6	±15	12.9	436	12.8	492	12.5	(10	12.6
+ibiasl	Ad		500	39.8	12.5	3500	12.6	389	12.4	395	12.8	399	13.1	392	12.8	400	12.5	410	13.6	455	12.2	435	12.6	415	12.8
+ibias2	nA		720	386	12.4	387	12.4	388	12.5	VIII	12.3	383	12.5	394	12.5	407	12.9	412	12.4	429	11.9	429	12.9	\$ 12	. 12.9
-ibias1	nΑ		700	380	12.1	3E2	12.3	388	12.3	38.5	11.9	393	12.3	401	13.3	412	13.8	419	13.8	434	11.0	433	13.9	419	12.8
-ibias2	υŊ		700	3.84	12.6	184	12.1	385	12.1	*: ::		0:2	4.4	5.5	3.4	0.23	3.3	1.3	4.01	0.6	2.5	07.8	4.1	0.5∋	3.5
iicl	nA	-100	100	Q.27 8	4.1	1.3	0.3	- 5.35	6.6	1.3	4.1	2.2	3.9	0.52	6.8	-1	3.3	-1	4.9	3.1	6.5	2.9	0.7	2.	6.1
11¢2	n.A	-100	100	0.12	3.1	4,3	10.4	0.06	3.6	243	0.6	478	£7.5	561	149	450	27.3	455	27.1	395	63.2	450	50.2	420	61.3
Aval	V/mV	250		592	117	:559:	. 170	519]	€4	53.3	84_	560	229	537	143	510	110	52.5	115	473	45.3	424	5 2	···· \$ %5	53.2
Avs2	V/mV	250		590	115	565	174	529	89	5ec	89		2.1	114	2.2	114	2.2	114	2.1	112	1.8	113	2.2	116	2.ε
cmrt1	ďΒ	85		334	1.7	±25	2.5	115	2.5	1114	2.5	713	2.1	113	2.31	113	2.1	114	2.3	113	1.9	114	2.4	114:	2.3
cmr2	dΒ	80		113	1.6	114	2.3	114	2.3	1115	2.3	112	9.4	212	7.5	109	7.8	110	7.7	108	7.7	111	9.2	111	6.5
+psrrl	cВ	80	Γ.	115	9.4	116	9.8	116	12.4	113	15.	114	5.5	#2	5.E	82	5.5	\$1.0	4.9	8.2	5.4	84.2	5.8	81.8	5.2
-psrr2	d3	90		83	6.1	68.8	7.7	63	11.5	52 2	5.5	82,1		101	4.9	101	5.6	101	5.7	370	5.0	100	4.2	131	4.5
-psrrl		80		10 2	4.2	107	4.3	.91	4.6	101	4.2	120	4.5	B1.1	5.9	81.9	4.8	81.6	4.7	€2	4.9	81.6	4.8	84	7.8
-psrr2	13	80		82.2	5.5	82.2	4.3	92	4.8	92	4.6	91.6	4.9	5, 557, 557, 5		-41:2	0,73	-4E.8	0.79	4 	0.58	-35.2	0.71	-41	0.6
+Iout1	m.R.	-50	0	941.B	0.69	4,3 7	0.68		3.6	- 62			0.73		1—		0.69		0.79		0.77	::¥37.e8	0,69	-39	0.7
+Iout2	лA	-50	0	+42	0.71	4.0 . 5	0.77		3,7	-41.6		1 2000000000000000000000000000000000000		3211 313411	0.81	42.3	0.79	1.407 0.007	0.61	11111111111	0.79		0.62	41	0.6
-fout1	mA	0	50	41.4	6.7	45.2	0.79	40	0.68	34.9		1	0.69	200 3032		100 100 100	0.31	41.3	0.65		0.83	_	0.81	41	0.7
-Iout2	πĀ	0	50	43.4	0.8	41.2	0.63	12	0.8	41.2	0.91	43	2.81	43.5	0.79	45.1	1,0.01	1 (F. 1978)	1.0.00	1	1	8877.73	1	<u> </u>	

^{1/} The mean and standard deviation values were calculated over the eight parts irradiated in this testing. The control samples remained constant throughout the testing and is not included in this table.

^{2/} These are manufacturer's non-irradiated data sheet specification limits. No post-irradiation limits were provided by the manufacturer at the time the tests were performed.

^{3/} The radiation sensitive parameters were Viol, +pssr2 and -psrr2.

Figure 1. Radiation Bias Circuit for EL2243C

